Computer Simulation of Flux Pinning in Type-II Suyerconduetors

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(Heceived 28 February 1983)

Random point pinning of ideal or defective flux-line lattices is simulated on a computer. For weak pins, Larkin and Ovchinnikov's two-dimensional collective pinning is confirmed: $j_c = \text{const} \times n_p \langle f_p^2 \rangle / R_p c_{66}$ (j_c is the critical current; n_p , f_p , and R_p are the density, force, and range of pins; and c_{66} is the shear modulus). The constant is determined. Defective lattices are pinned more strongly by factors 1.3 to 3, explaining the observed history effect. A pronounced jump in the curves $j_c(f_b)$ indicates the onset of plastic deformation.

PACS numbers: 74.60.Ge

The statistical summation of pinning forces in type-II superconductors is still a controversial problem. The theory of Labusch,¹ conceived for widely spaced random point pins, appears to disagree with many experiments and to be inconsistent. $2-4$ A pinning threshold predicted by this "dilute limit" theory and its improved versions' has been reported only once⁵ but usually is absent in experiments. Recently, Larkin and Ovchinnikov 6 (LO) proposed a theory of "collective pinning" which was widely believed to underestimate the critical current j_c even more than previous theories. The situation changed very recently when collective pinning, in its twodimensional (2D) form, was confirmed with high accuracy on sputtered thin films of amorphous $Nb₃Ge$ and $Nb₃Si$ with extremely weak pinning by Kes and Tsuei.⁷ The agreement of experiments with the 3D LO theory improved considerably when Thuneberg, Kukijärvi and Rainer⁸ showed that the correct microscopic treatment yields elementary pinning forces f_p which are larger than assumed so far.

In this Letter I report on 2D computer simulations of flux pinning which give the following answers to long-standing questions: (a) The 2D LO result, $j_c \sim f_p^2$, is confirmed for weak, and in some cases for arbitrarily strong, pinning. (b) Some functions $j_c(f_p)$ exhibit a pronounced jump but not a genuine threshold. (c) The history effect⁸ is due to much stronger pinning of a defective ("amorphous") flux-line lattice (FLL) as compared to the ideal FLL. (d) The observed steep initial slope of the force-displacement curves⁹ is reproduced. (e) For strong pinning the existence of a (modified) direct summation the existence of a (modified) direct summation
limit, $j_c \sim f_p$, is confirmed. (f) The concept of elementary pinning forces should be modified: In order to have simple laws $j_c \propto f_p^2$ and $j_c \propto f_p$ in a large range of pinning strengths, one has to

interpret f_{ρ} as the root-mean-square pinning force rather than (as is usually assumed) the maximum force, $f_{\text{max}} \approx A_p/R_p$, exerted by a pin with interaction range R_p and amplitude A_p . Depending on the type of pins, relaxation may reduce or enhance f_{ρ} from its rigid-lattice value. Typical curves $j_c(f_{\text{max}})$ for attracitve pins exhibit a quadratic region (weak, collective pinning), a jump (onset of plastic FLL deformation), a. flat region (flux-line trapping), and a linear, very strong-pinning region.

These results are expected to apply qualitative ly also to 3D pinning, apart from the weak-pinning law for which a 30 simulation should yield^{6,10,11} $j_c \propto f_b^4$. As noticed first by Kes,¹² the LO theory predicts a change of dimensionality, $3D-2D$, when pinning in a film or ribbon (perpendicular to an applied magnetic field) becomes sufficiently weak for the correlation length along the field, L_c , to exceed the film thickness d. In this case our 2D simulation becomes $quan$ titative and may help to identify the pins in a given mater ial.

Our simulation starts from the total energy per unit length

$$
U = \sum_{i} \sum_{j \neq i} V_{v}(|\vec{\mathbf{r}}_{i} - \vec{\mathbf{r}}_{j}|) + \sum_{i} \sum_{j} V_{p}(|\vec{\mathbf{r}}_{i} - \vec{\mathbf{r}}_{j}^{(\rho)}|)
$$
\n(1)

of a system of N_v vortices with variable positions $\vec{r}_i=(x_i; y_i)$ and N_p pins with fixed random positions $\mathbf{\vec{r}}_i{}^{(p)}$ in a roughly quadratic basic area A. $=L_x L_y$ with periodic boundary positions. Instead of using the correct interaction potentials be-
tween vortices, $^{13, 14}$ $V_p(r)$, and between vortic tween vortices, ^{13, 14} $V_v(r)$, and between vortice
and point pins, ¹⁵ $V_v(r)$, for better transparency and point pins, 15 $V_p(r)$, for better transparenc we choose Gaussian-like potentials,

$$
V_{\nu}(r) = A_{\nu} v(r/R_{\nu}), \quad V_{\rho}(r) = A_{\rho} v(r/R_{\rho}),
$$

$$
v(\rho) \approx \exp(-\rho^2).
$$
 (2)

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FIG. 1. Mean pinning force $F(X)$ (solid line) and mean square pinning force $W(X)$ (dashed line) vs mean X coordinate of the vortices for $N_v = 780$, $N_b = 210$, $R_v = 0.6$, $R_p = 0.25$, and pin amplitude $A_p = -0.02$, -0.05 , -0.07 , -0.1 , and -0.2 (attractive pins). The numbers on the left (right) denote the maximum and minimum of F (W) in the plotted interval, and the averages \overline{F} (\overline{W}) over a much larger interval. Straight lines indicate $F = 0$ and the initial slope of $F(X)$.

We fix our energy and length scales by putting $A_v = 1$ and $a₀ = 1$ (the flux-line spacing). The system is then characterized by five essential parameters: N_v , N_p , R_v , R_p , and A_p . The vortex range $R_v = 0.6$ (0.7, 0.75) determines the shear and compression moduli of the FLL, $c_{66} = 0.2695$ $(0.1411, 0.0831)$ and $c_{11} = 1.994$ (2.345, 2.523) $\gg c_{66}$. Physically, R_v , R_p , and A_p are related to the reduced induction $b = B/B_{c2}$ and to the Ginsburg-Landau parameter κ . For example, c_{66}/c_{11} $\approx (1-b)^2/10b\kappa^2$ ($\kappa^2 \gg 1$, $b \gg 1/2\kappa^2$), for vortexcore pinning $R_p \approx 0.53b^{1/2}$; and near $b = 1$ we find A_b = const \times (1 – b) and A_b/c_{66} = const/(1 – b) (our main parameter).

At least 72 qualitatively different eases may be distinguished: The pins may be dilute, matching, or dense $(N_p/N_v \ll 1, \approx 1, \text{ or } \gg 1)$, sharp or smooth $(R_h < 0.3$ or $> 0.3)$, repulsive or attractive $(A_{\nu} > 0 \text{ or } < 0)$, and strong or weak $(A_{\nu}/c_{\text{eq}}R_{\nu})$ >1 or $<$ 1); the initial vortex positions may be ideal triangular FLL with two possible orientations, or amorphous (generated by relaxing random positions). From ≈ 900 cases investigated so far, I present in Figs. I and ² the results of forty runs with $N_p = 780$, $N_p = 210$, $R_p = 0.6$, and R_{b} = 0.25 (attractive and repulsive point pins of

FIG. 2. The averages over X , \overline{F} (solid line, interpreted as j_c) and \overline{W} (short dashes), the direct-summation limits F_d and \hat{F}_d , Eq. (4) (dotted lines) (left scale), and the ratio $\overline{F}/\overline{W}$ (long dashes) and the root-mean-square vortex displacement at $X = 1.2$, σ (dash-dotted line) (right scale), plotted vs the pin amplitude A_{ρ} . The curves \overline{F} and \overline{W} denoted by "am." are for the amorphous lattice; all other curves are for the ideal lattice or independent of the lattice perfection. The parameters N_v , N_p , R_v , and R_p are as in Fig. 1; (a) attractive pins, (b) repulsive pins.

medium density).

Pinning is simulated in the following way: First the pins are switched on and the FLL is relaxed by minimizing (1). Starting from this virgin state, with $\langle \vec{r}_i \rangle = 0$ by definition, the FLL is shifted homogeneously a small distance dX $\approx 0.001 - 0.0001$ along $\hat{\vec{x}}$; then the total pinning force is compensated by a homogeneous driving force F acting along $\hat{\bar{x}}$ on each flux line, and the FLL is relaxed by minimizing the function ^G $= U - N_{\nu} F X$ where $X = \langle x_i \rangle$ is the mean x coordinate of the flux lines. By repeating this procedure we should obtain static (i.e., fully relaxed
force-displacement curves $F(X)$ (Fig. 1) 16,17 force-displacement curves $F(X)$ (Fig. 1).^{16,17} For weak pinning, $F(X)$ is smooth and periodic, with period a_0 for $\hat{\bar{x}} \parallel \langle 10 \rangle$ and $3^{1/2} a_0$ for $\hat{\bar{x}} \parallel \langle 11 \rangle$. Transient effects slightly "compress" the first periods of $F(X)$. For stronger pinning, $F(X)$ increases first linearly and then fluctuates about its average value \overline{F} . If X is oscillated we obtain hysteresis curves oscillating between $+\overline{F}$ and $-\overline{F}$. For comparison with summation theories we calculate also the mean square pinning force $W(X)$ and its average \bar{W} . Since the fluctuations of $F(X)$ and $W(X)$ decrease with increasing N_v and N_{ν} , we may relate \overline{F} and \overline{W} to j_c and to the quantity $W(0)$ (Refs. 6 and 7) of large specimens:

$$
j_{c} B = n \overline{F} = n_{p} \langle \langle -\hat{\vec{x}} \cdot \vec{f}_{j}(X) \rangle \rangle,
$$

$$
W(0) / d = n \overline{W} = n_{p} \langle \langle |\vec{f}_{j}(X)|^{2} \rangle \rangle,
$$
 (3)

where $n = N_v / A = B / \varphi_0 = \frac{2}{3}^{1/2} a_0^2$ and $n_p = N_p / A$ are the densities of vortices and pins, $\mathbf{\vec{f}}_i = \partial U / \partial \mathbf{\vec{r}}_i$ ^(\mathbf{r}) is the force exerted by the ith pin, and the averages are over j and X .

Figure 2 shows $\overline{F}(A_{p}), \ \overline{W}(A_{p}), \ \overline{F}/\overline{W}$, and the direct summation limit in its old (F_d) and improved¹⁴ (\hat{F}_d) versions,

$$
F_{d} \equiv n_{p} f_{\text{max}} / n = (2/e)^{1/2} N_{p} A_{p} / N_{v} R_{p} ,
$$

$$
\hat{F}_{d} \equiv n_{p} f_{p} / n = (N_{p} \overline{W} / N_{v})^{1/2} .
$$
 (4)

Note that the limit \hat{F}_d is almost reached: \overline{F} $\leq 0.54\hat{F}_{d}$ for attractive pins, and $\overline{F} \leq 0.42\hat{F}_{d}$ for repulsive pins. The limit F_d is much too high, and for repulsive pins even makes no sense. For repulsive pins \overline{W} is always below its rigid-lattice (weak pinning) limit, 14 $\pi n_{\rho}A_{\rho}^{2}$, whereas for attractive pins the ratio $\overline{W}/\pi n_{_{\bm{P}}} A_{_{\bm{P}}}^{-2}$ exceeds unity, goes through a flat maximum ≈ 1.3 at $A_p \approx -0.07$ in Fig. 2(a)], and then drops below unity [at A_{ρ} $= -0.135$ in Fig. 2(a)].

The perhaps most striking feature is a pronounced jump of $F(A_{p})$ occurring in Fig. 2(a) almost exactly at the *threshold* value $A_p = -0.071$ predicted from the onset of elastic instabilities $f_{\rm predicted}$ from the onset of elastic instabilitifor the isolated pin.^{1,3,5} For short-range ($R_{\rm p}$ (0.3) attractive Gaussian pin potential (2) this threshold is at^{14}

$$
A_{\text{thr}} = 2\pi \exp(\frac{3}{2})c_{66}R_{\rho}^{2}/\ln(N_{\nu}).
$$
 (5)

This jump is most clearly seen in the (linearly plotted) functions \bar{F}/\bar{W} and $\sigma = \langle |\vec{s} - \langle \vec{s} \rangle|^2 \rangle^{1/2}$ (the root-mean-square vortex displacement at $X = 1.2$). The increase of σ indicates the onset of plastic FLL deformation, a conjecture which is confirmed by plots of the vortex and pin positions. Note also the "slowing down" of the fluctuations of $F(X)$ at $A_b = 0.07$ in Fig. 1. The character of $F(X)$ changes just at the jump of \overline{F} , again indicating the transition from the "elastic" to the "plastic" range. A similar jump in $\overline{F}/\overline{W}$ occurs for repulsive pins in Fig. $2(b)$. The transition is broader and starts at a value $A_p \approx 0.3$ which is somewhat smaller than the threshol
for repulsive pins, 14 A_{rlu} ≈ 0.7 in this case. I for repulsive pins, 14 A $_{\rm thr}$ \approx 0.7 in this case. If we start with an amorphous FLL the jump is absent or of smaller amplitude, indicating that our amorphous FLL cannot become much more defective.

For weak pinning the 2D LO result $\overline{F}/\overline{W}$ = const is confirmed both for the ideal and for the amorphous FLL. For the ideal FLL we obtain

$$
\overline{F}/\overline{W} = 0.035[\ln(N_v/33)]^{1/2}R_p c_{66}.
$$
 (6)

The dependence on R_{p} and c_{66} is well established for $0.6 \le R_v \le 0.75$ and $0.0625 \le R_v \le 0.4$. For R_v <0.6 or $R_b > 0.4$ compression of the FLL may not be neglected and $\overline{F}/\overline{W}$ depends on c_{66} and c_{11} . Note that for sharp point pins $(R_e \ll 1)$ the effective force range is *not* half the vortex spacing [i.e., R_p replaced by $\frac{1}{2}$ in (6)] as is sometime assumed. For very weak point pins, $\overline{W} = \pi n_p A_p^2$ is independent of R_{ν} but

$$
\bar{F} \approx 0.11 [\ln(N_v/33)]^{1/2} n_p A_p^2 / R_p c_{66}
$$

depends on R_{ρ} . The logarithmic factor $ln(N_{\nu}/33)$ $\approx \ln(L_x L_y / 9a_0^2)$ is approximate (for 0.005 $\leq A_p$) ≤ 0.05) and according to the LO theory^{6,7} should slightly depend on A_{p} .

From (3) and {6) we get the 2D collective pinning formula

$$
j_c B = W(0) [\ln(R/3a_0)]^{1/2} / 20 R_p d c_{66}
$$
 (7)

which, in contrast to LO's estimate, contains a numerically determined prefactor $(d \text{ and } 2R \text{ are})$ the specimen thickness and width). Equations (6) and (7) apply also to the amorphous FLL if the right-hand sides are multiplied by a factor 1.3

to 3. The enhancement of pinning by the presence of FLL defects usually is considerably larger than the effect of a reduction of c_{66} , which from 3D simulations of amorphous metals is expected to be of the order of 30% . Since defectenhanced pinning causes the history effect⁸ and presumably also the peak in $j_c(B)$ observed near $b = 1$ in Ref. 7, the detailed investigation of its mechanism appears to me one of the challenging problems which computer simulations should be able to solve in the near future.

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 16 Dynamic force-velocity curves (interpreted as current-voltage curves) will be given elsewhere.

¹⁷ For one-dimensional simulations see J. R. Appleyard, J. E. Evetts, and A. M. Campbell, Solid State Commun. 14, 567 (1974).